

# Numerical Problem

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- In a 100ns pulse,  $6 \times 10^6$  photons at a wavelength 1300 nm absorbed by a InGaAs photodetector. On the average  $3.9 \times 10^6$  electron hole pairs are generated. Calculate the quantum efficiency

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$$\eta = 0.65 = 65\%$$

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- Photons of energy  $1.53 \times 10^{-19}$  J are incident on a photodiode which has a responsivity of 0.65 A/W. If the optical power level is 10  $\mu$ W, calculate the generated photocurrent.

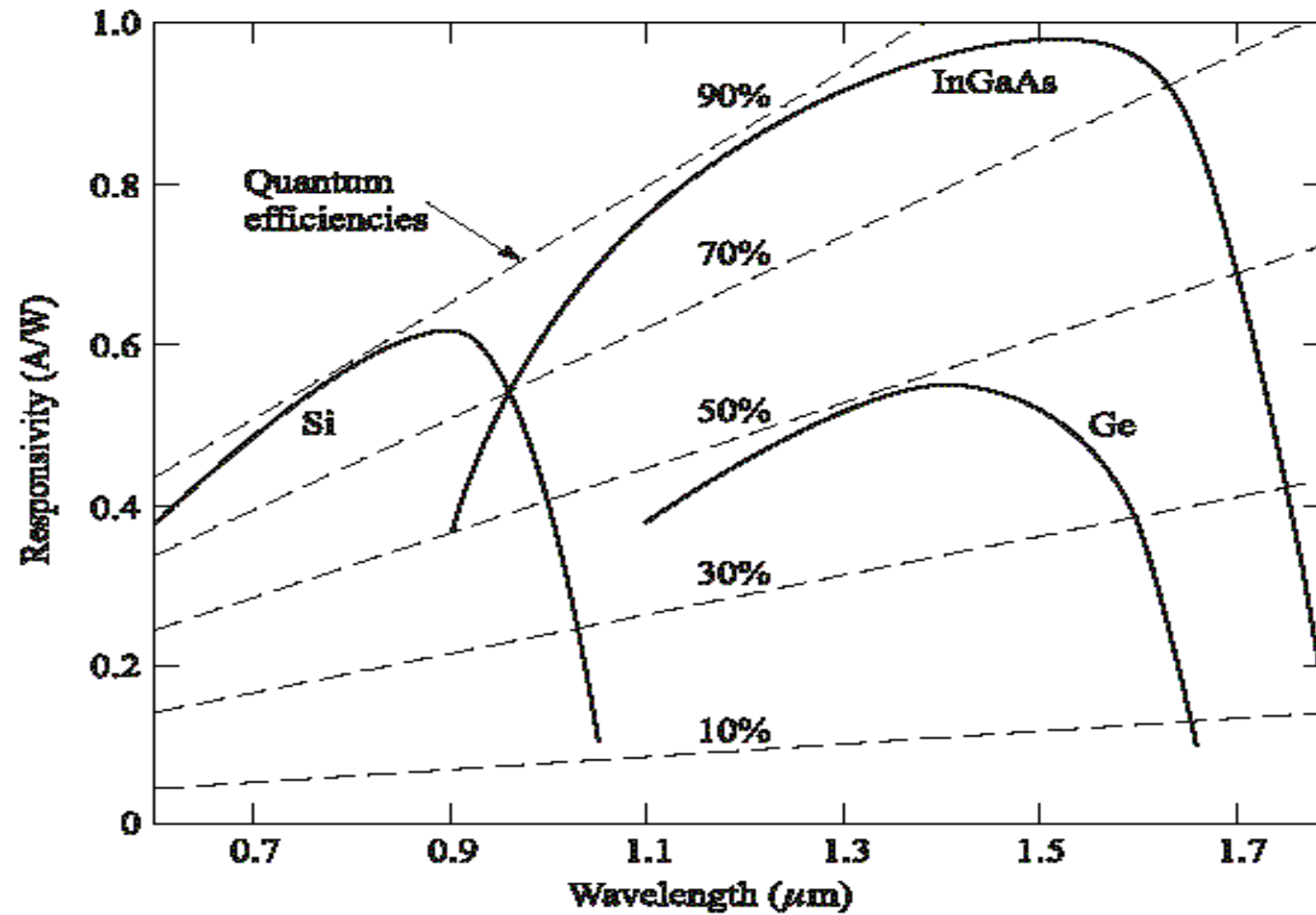
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$$I_p = RP_0 = 6.5 \mu A$$

# Photodiode Responsivities



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- In the above figure, for the wavelength range  $1100 \text{ nm} < \lambda < 1600 \text{ nm}$ , the quantum efficiency for InGaAS diode is about 60 %. Calculate the responsivity in this wavelength.

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$$R = \frac{\eta q}{h \nu} = 4.83 * 10^5 \lambda$$

$$R = 0.63 \text{ A/W}$$

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- When  $3 \times 10^{11}$  photons each with a wavelength of  $0.85 \mu\text{m}$  are incident on a photodiode, on average  $1.2 \times 10^{11}$  electrons are collected at the terminals of the diode. Determine the quantum efficiency and responsivity of the photodiode at  $0.85 \mu\text{m}$ .



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$$\eta = 0.4 = 40\%$$

$$R = \frac{\eta q}{h \nu} = 0.274 \text{ A / W}$$

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- A silicon APD has a quantum efficiency of 65 % at a wavelength of 900 nm. If the multiplication factor is 35 and the incident optical power is  $0.5 \mu\text{W}$ , find the multiplied output photo current.

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- A silicon APD has a quantum efficiency of 55 % at a wavelength of 900 nm. If the multiplication factor is 35 and the incident optical power is 0.7  $\mu\text{W}$ , find the multiplied output photo current.

$$I_p = RP_0 = \frac{\eta q}{h\nu} P_0 = 0.279 \mu\text{A}$$

$$I_M = MI_P = 9.765 \mu\text{A}$$

# Numerical Problem

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- A Si pin photodiode has a quantum efficiency of 70% at a wavelength of 0.85  $\mu\text{m}$ . Calculate its responsivity.
- Calculate the responsivity of a Germanium diode at 1.6  $\mu\text{m}$  where its quantum efficiency is 40%.
- A particular photodetector has a responsivity of 0.6 A/W for light of wavelength 1.3  $\mu\text{m}$ . Calculate its quantum efficiency.

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$$R = \frac{\eta \lambda (\mu\text{m})}{1.24} = \frac{0.7 \times 0.85}{1.24} = 0.48 \text{ A/W}$$

$$R = \frac{\eta \lambda (\mu\text{m})}{1.24} = \frac{0.4 \times 1.6}{1.24} = 0.52 \text{ A/W}$$

$$\eta = \frac{R \cdot 1.24}{\lambda (\mu\text{m})} = \frac{0.6 \times 1.24}{1.3} = 57\%$$